



DDR3 SDRAM High-Performance Controller User Guide



101 Innovation Drive
San Jose, CA 95134
www.altera.com

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Release Information

Table 1–1 provides information about this release of the DDR3 SDRAM High-Performance Controller MegaCore® functions.

Table 1–1. DDR3 SDRAM High-Performance Controller Release Information

Item	Description
Version	9.0
Release Date	March 2009
Ordering Codes	IP-SDRAM/DDR3
Product IDs	00C2 00CO (ALTMEMPHY Megafunction)
Vendor ID	6AF7

Altera® verifies that the current version of the Quartus® II software compiles the previous version of each MegaCore function. The *MegaCore IP Library Release Notes and Errata* report any exceptions to this verification. Altera does not verify compilation with MegaCore function versions older than one release.

Device Family Support

MegaCore functions provide either full or preliminary support for target Altera device families, as described below:

- *Full support* means the MegaCore function meets all functional and timing requirements for the device family and may be used in production designs
- *Preliminary support* means the MegaCore function meets all functional requirements, but may still be undergoing timing analysis for the device family; it may be used in production designs with caution

Table 1–2 shows the level of support offered by the DDR3 SDRAM High-Performance controller to each of the Altera device families.

Table 1–2. Device Family Support

Device Family	Support
Arria® II GX	Preliminary
Stratix® III	Full
Stratix IV	Preliminary
HardCopy® III	Preliminary
HardCopy IV E	Preliminary
Other device families	No support

Features

- Integrated error correction coding (ECC) function
- Power-up calibrated on-chip termination (OCT) support
- Half-rate support for Stratix III and Stratix IV devices
- SOPC Builder ready
- Automatically generated memory simulation model simplifies simulation flow
- Support for ALTMEMPHY megafunction
- Support for industry-standard DDR3 SDRAM devices and modules
- Optional support for self-refresh and power-down commands
- Optional support for auto-precharge read and auto-precharge write commands
- Optional user-controller refresh
- Optional Avalon® Memory-Mapped (Avalon-MM) local interface
- Easy-to-use MegaWizard™ interface
- Support for OpenCore Plus evaluation
- Support for the Quartus II IP Advisor
- IP functional simulation models for use in Altera-supported VHDL and Verilog HDL simulators

General Description

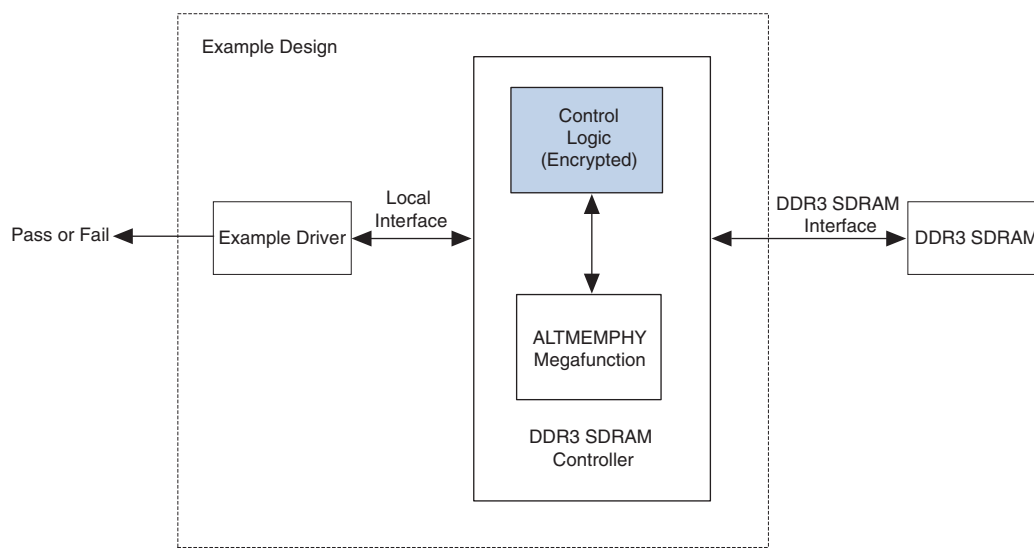
The Altera DDR3 SDRAM High-Performance Controller MegaCore functions provide simplified interfaces to industry-standard DDR3 SDRAM. The MegaCore functions work in conjunction with the Altera ALTMEMPHY megafunction.



For more information on the ALTMEMPHY megafunction, refer to the *External Memory PHY Interface Megafunction User Guide (ALTMEMPHY)*.

Figure 1-1 on page 1-3 shows a system-level diagram including the example design that the DDR3 SDRAM High-Performance Controller MegaCore functions create for you.

Figure 1–1. System-Level Diagram



The MegaWizard Plug-In Manager generates an example design that instantiates an example driver and your DDR3 SDRAM high-performance controller custom variation. The controller instantiates an instance of the ALTMEMPHY megafunction which in turn instantiates a PLL and DLL. You can optionally instantiate the DLL outside the ALTMEMPHY megafunction in order to share the DLL between multiple instances of the ALTMEMPHY megafunction.

The example design is a fully-functional design that you can simulate, synthesize, and use in hardware. The example driver is a self-test module that issues read and write commands to the controller and checks the read data to produce the pass/fail and test complete signals.

MegaCore Verification

MegaCore verification involves simulation testing. Altera performs extensive random, directed tests with functional test coverage using industry-standard Denali models to ensure the functionality of the DDR3 SDRAM high-performance controller. In addition, Altera has carried out a wide variety of gate-level tests of the DDR3 SDRAM high-performance controller to verify the post-compilation functionality of the controller.

Performance and Resource Utilization

Table 1-3 shows maximum performance results for the DDR3 SDRAM high-performance controller using the Quartus II software, version 9.0.

Table 1-3. Maximum Performance for DDR3 Half Rate Controller

Device	Rate	System fMAX (MHz)
Stratix III	Half Rate	533
Stratix IV	Half Rate	533

 For more information on device performance, refer to the relevant device handbook.

Table 1-4 shows typical sizes for the DDR3 SDRAM high-performance controller on Stratix III and Stratix IV devices.

Table 1-4. Typical Size—Stratix III & Stratix IV Devices

Local Data Width (Bits)	Memory Width (Bits)	Combinational ALUTs	Dedicated Logic Registers	Memory (M9K)
32	8	4,416	3,199	3
64	16	5,012	3,735	4
256	32	8,365	6,806	13
288	64	8,945	7,319	14

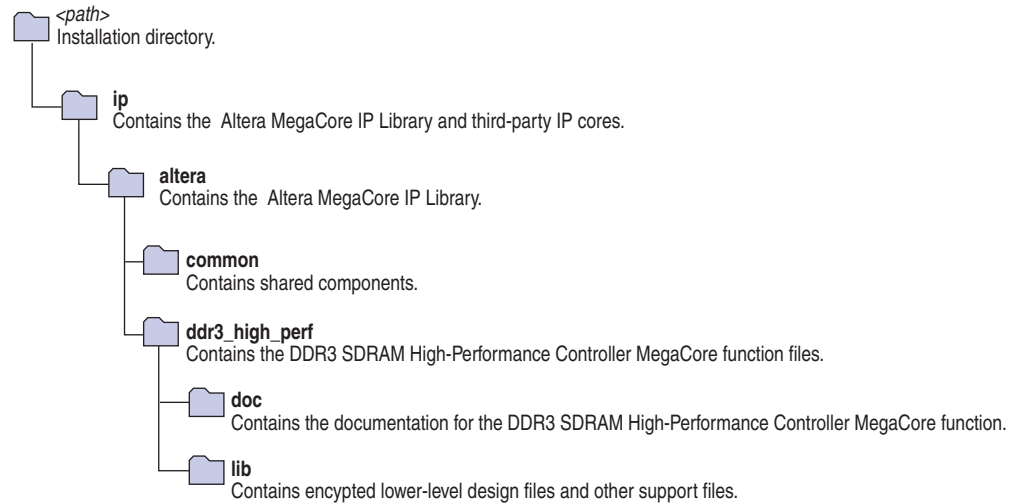
Installation and Licensing

The DDR3 SDRAM High-Performance Controller MegaCore functions are part of the MegaCore IP Library, which is distributed with the Quartus II software and downloadable from the Altera website, www.altera.com.

 For system requirements and installation instructions, refer to *Quartus II Installation & Licensing for Windows and Linux Workstations*.

Figure 1-2 shows the directory structure after you install the DDR3 SDRAM High-Performance Controller MegaCore functions, where *<path>* is the installation directory. The default installation directory on Windows is `c:\altera\<version>`; on Linux it is `/opt/altera<version>`.

Figure 1–2. Directory Structure



You need a license for the MegaCore function only when you are completely satisfied with its functionality and performance, and want to take your design to production.


If you want to use the DDR3 SDRAM High-Performance Controller MegaCore function, you can request a license file from the Altera web site at www.altera.com/licensing and install it on your computer. When you request a license file, Altera emails you a **license.dat** file. If you do not have Internet access, contact your local Altera representative.

OpenCore Plus Evaluation

With Altera's free OpenCore Plus evaluation feature, you can perform the following actions:

- Simulate the behavior of a megafunction (Altera MegaCore function or AMPPSM megafunction) within your system
- Verify the functionality of your design, as well as evaluate its size and speed quickly and easily
- Generate time-limited device programming files for designs that include MegaCore functions
- Program a device and verify your design in hardware

You need to purchase a license for the megafunction only when you are completely satisfied with its functionality and performance, and want to take your design to production.

 For more information on OpenCore Plus hardware evaluation using the DDR3 SDRAM high-performance controller, refer to *AN 320: OpenCore Plus Evaluation of Megafunctions*.

OpenCore Plus Time-Out Behavior

OpenCore Plus hardware evaluation can support the following two modes of operation:

- Untethered—the design runs for a limited time
- Tethered—requires a connection between your board and the host computer. If tethered mode is supported by all megafunctions in a design, the device can operate for a longer time or indefinitely

All megafunctions in a device time out simultaneously when the most restrictive evaluation time is reached. If there is more than one megafunction in a design, a specific megafunction's time-out behavior may be masked by the time-out behavior of the other megafunctions.



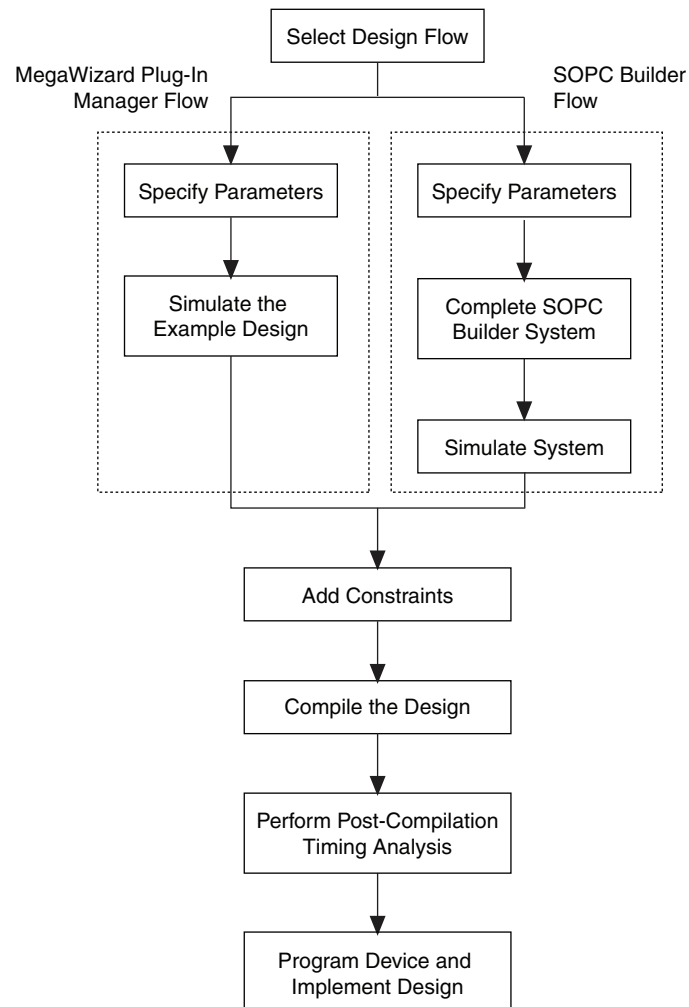
For MegaCore functions, the untethered time-out is 1 hour; the tethered time-out value is indefinite.

Your design stops working after the hardware evaluation time expires and the `local_ready` output goes low.

Design Flow

Figure 2–1 shows the stages for creating a system with the DDR3 SDRAM High-Performance Controller MegaCore function and the Quartus II software. The sections in this chapter describe each stage.

Figure 2–1. Design Flow



Select Flow

You can parameterize the DDR3 SDRAM High-Performance Controller MegaCore function using either one of the following flows:

- SOPC Builder flow
- MegaWizard Plug-In Manager flow

Table 2–1 summarizes the advantages offered by the different parameterization flows.

Table 2–1. Advantages of the Parameterization Flows

SOPC Builder Flow	MegaWizard Plug-In Manager Flow
<ul style="list-style-type: none"> ■ Automatically-generated simulation environment ■ Create custom components and integrate them via the component wizard ■ All components are automatically interconnected with the Avalon-MM interface 	<ul style="list-style-type: none"> ■ Design directly from the DDR3 SDRAM interface to peripheral device(s) ■ Achieves higher-frequency operation

SOPC Builder Flow

The SOPC Builder flow allows you to add the DDR3 SDRAM High-Performance Controller MegaCore function directly to a new or existing SOPC Builder system. You can also easily add other available components to quickly create an SOPC Builder system with a DDR3 SDRAM High-Performance Controller, such as the Nios II processor, external memory controllers, and scatter/gather DMA controllers. SOPC Builder automatically creates the system interconnect logic and system simulation environment.



For more information about SOPC Builder, refer to [volume 4](#) of the *Quartus II Handbook*. For more information about how to use controllers with SOPC Builder, refer to [AN 517: Using High-Performance DDR, DDR2 and DDR3 SDRAM With SOPC Builder](#). For more information on the Quartus II software, refer to the Quartus II Help.

Specify Parameters

To specify DDR3 SDRAM High-Performance Controller parameters using the SOPC Builder flow, follow these steps:

1. In the Quartus II software, create a new Quartus II project with the **New Project Wizard**.
2. On the Tools menu, click **SOPC Builder**.
3. For a new system, specify the system name and language.
4. Add **DDR3 SDRAM High-Performance Controller** to your system from the **System Contents** tab.



The **DDR3 SDRAM High-Performance Controller** is in the **SDRAM** folder under the **Memories and Memory Controllers** folder.

5. Specify the required parameters on all pages in the **Parameter Settings** tab.



For detailed explanation of the parameters, refer to the “[Parameter Settings](#)” on page 3-1.

6. Click **Finish** to complete the DDR3 SDRAM High-Performance Controller MegaCore function and add it to the system.

Complete the SOPC Builder System

To complete the SOPC Builder system, follow these steps:

1. In the **System Contents** tab, select **Nios II Processor** and click **Add**.
2. On the **Nios II Processor** page, in the **Core Nios II** tab, select **altmemddr** for **Reset Vector** and **Exception Vector**.
3. Change the **Reset Vector Offset** and the **Exception Vector Offset** to an Avalon address that is not written to by the ALTMEMPHY megafunction during its calibration process.



The ALTMEMPHY megafunction performs memory interface calibration every time it is reset and in doing so writes to addresses 0x0 to 0x47. If you want your memory contents to remain intact through a system reset, you should avoid using the memory addresses below 0x48. This step is not necessary, if you reload your SDRAM memory contents from flash every time you reset.

To calculate the Avalon-MM address equivalent of the memory address range 0x0 to 0x47, multiply the memory address by the width of the memory interface data bus in bytes. For example, if your external memory data width is 8 bits, then the **Reset Vector Offset** should be 0x60 and the **Exception Vector Offset** should be 0x80.

External Memory Interface Width	Reset Vector Offset	Exception Vector Offset
8	0x60	0x80
16	0xA0	0xC0
32	0x120	0x140
64	0x240	0x260

4. Click **Finish**.
5. On the **System Contents** tab, expand **Interface Protocols** and expand **Serial**.
6. Select **JTAG UART** and click **Add**.
7. Click **Finish**.



If there are warnings about overlapping addresses, on the System menu click **Auto Assign Base Addresses**.

If you enable ECC and there are warnings about overlapping IRQs, on the System menu click **Auto Assign IRQs**.

8. For this example system, ensure all the other modules are clocked on the `altmemddr_sysclk`, to avoid any unnecessary clock-domain crossing logic.
9. Click **Generate**.



Among the files generated by SOPC Builder is the Quartus II IP File (**.qip**). This file contains information about a generated IP core or system. In most cases, the **.qip** file contains all of the necessary assignments and information required to process the MegaCore function or system in the Quartus II compiler. Generally, a single **.qip** file is generated for each SOPC Builder system. However, some more complex SOPC Builder components generate a separate **.qip** file. In that case, the system **.qip** file references the component **.qip** file.

10. To ensure the automatically-generated constraints function correctly, you must ensure the pin names and pin group assignments match, otherwise the design may not fit when you compile your design. You can either create your own top-level design file or edit the `altmemddr_example_top.v` file to replace the example driver and the DDR3 SDRAM High-Performance controller, and instantiate your SOPC Builder-generated system.

Simulate the System

During system generation, SOPC Builder optionally generates a simulation model and testbench for the entire system, which you can use to easily simulate your system in any of Altera's supported simulation tools. SOPC Builder also generates a set of ModelSim® Tcl scripts and macros that you can use to compile the testbench, IP functional simulation models, and plain-text RTL design files that describe your system in the ModelSim simulation software.



For more information about simulating the SOPC Builder system, refer to [volume 4](#) of the *Quartus II Handbook* or [AN 351: Simulating Nios II Systems](#).

MegaWizard Plug-In Manager Flow

The MegaWizard Plug-In Manager flow allows you to customize the DDR3 SDRAM High-Performance Controller MegaCore function, and manually integrate the function into your design.



You can alternatively use the IP Advisor to help you start your DDR3 SDRAM High-Performance Controller MegaCore design. On the Quartus II Tools menu, point to **Advisors**, and then click **IP Advisor**. The IP Advisor guides you through a series of recommendations for selecting, parameterizing, evaluating, and instantiating a DDR3 SDRAM High-Performance Controller MegaCore function into your design. It then guides you through a complete Quartus II compilation of your project.



For more information about the MegaWizard Plug-In Manager and the IP Advisor, refer to the Quartus II Help.

Specify Parameters

To specify DDR3 SDRAM High-Performance Controller parameters using the MegaWizard Plug-In Manager flow, follow these steps:

1. In the Quartus II software, create a new Quartus II project with the **New Project Wizard**.
2. On the Tools menu, click **MegaWizard Plug-In Manager** and follow the steps to start the MegaWizard Plug-In Manager.



The DDR3 SDRAM High-Performance Controller MegaCore function is in the **Interfaces** folder under the **Memory Controllers** folder.

3. Specify the parameters on all pages in the **Parameter Settings** tab.



For detailed explanation of the parameters, refer to the “[Parameter Settings](#)” on page 3-1.

4. On the **EDA** tab, turn on **Generate simulation model** to generate an IP functional simulation model for the MegaCore function in the selected language.

An IP functional simulation model is a cycle-accurate VHDL or Verilog HDL model produced by the Quartus II software.



Use the simulation models only for simulation and not for synthesis or any other purposes. Using these models for synthesis creates a nonfunctional design.



Some third-party synthesis tools can use a netlist that contains only the structure of the MegaCore function, but not detailed logic, to optimize performance of the design that contains the MegaCore function. If your synthesis tool supports this feature, turn on **Generate netlist**.



The memory model generated by the wizard cannot be used if you select **Full Calibration (long simulation time)**. You must use a memory-vendor provided memory model.

5. On the **Summary** tab, select the files you want to generate. A gray checkmark indicates a file that is automatically generated. All other files are optional.



For more information about the files generated in your project directory, refer to [Table 2-2](#).

6. Click **Finish** to generate the MegaCore function and supporting files.
7. If you generate the MegaCore function instance in a Quartus II project, you are prompted to add the **.qip** files to the current Quartus II project. When prompted to add the **.qip** files to your project, click **Yes**. The addition of the **.qip** files enables their visibility to Nativelink. Nativelink requires the **.qip** files to include libraries for simulation.



The **.qip** file is generated by the MegaWizard interface, and contains information about the generated IP core. In most cases, the **.qip** file contains all of the necessary assignments and information required to process the MegaCore function or system in the Quartus II compiler. The MegaWizard interface generates a single **.qip** file for each MegaCore function.

8. After you review the generation report, click **Exit** to close the MegaWizard Plug-In Manager.

Table 2-2 describes the generated files and other files (AFI mode) that may be in your project directory. The names and types of files specified in the MegaWizard Plug-In Manager report vary based on whether you created your design with VHDL or Verilog HDL.

Table 2-2. Generated Files (Part 1 of 3)

Filename	Description
<i><variation name>.bsf</i>	Quartus II symbol file for the MegaCore function variation. You can use this file in the Quartus II block diagram editor.
<i><variation name>.html</i>	MegaCore function report file.
<i><variation name>.v</i> or <i>.vhd</i>	A MegaCore function variation file, which defines a VHDL or Verilog HDL top-level description of the custom MegaCore function. Instantiate the entity defined by this file inside of your design. Include this file when compiling your design in the Quartus II software.
<i><variation name>.qip</i>	Contains Quartus II project information for your MegaCore function variations.
<i><variation name>.ppf</i>	This XML file describes the MegaCore pin attributes to the Quartus II Pin Planner. MegaCore pin attributes include pin direction, location, I/O standard assignments, and drive strength. If you launch IP Toolbench outside of the Pin Planner application, you must explicitly load this file to use Pin Planner.
<i><variation name>_auk_ddr3_hp_controller_wrapper.vo</i> or <i>.vho</i>	VHDL or Verilog HDL IP functional simulation model.
<i><variation name>_example_driver.v</i> or <i>.vhd</i>	Example self-checking test generator that matches your variation.
<i><variation name>_example_top.v</i> or <i>.vhd</i>	Example top-level design file that you should set as your Quartus II project top level. Instantiates the example driver and the controller.
<i><variation name>_example_top_tb.v</i> or <i>.vhd</i>	Example testbench that instantiates the example top-level design file and the example memory model.
alt_mem_phy_defines.v	Contains constants used in the interface. This file is always in Verilog HDL regardless of the language you chose in the MegaWizard Plug-In Manager.
<i><variation_name>_phy.html</i>	Lists the top-level files created and ports used in the megafunction.
<i><variation_name>_phy.v</i> or <i>.vhd</i>	Top-level file of your ALTMEMPHY variation, generated based on the language you chose in the MegaWizard Plug-In Manager.
<i><variation_name>_phy.vho</i>	Contains functional simulation model for VHDL only.

Table 2-2. Generated Files (Part 2 of 3)

Filename	Description
<variation_name>_phy_alt_mem_phy_delay.vhd	Includes a delay module for simulation. This file is only generated if you choose VHDL as the language of your MegaWizard Plug-In Manager output files.
<variation_name>_phy_alt_mem_phy_dq_dqs.vhd or .v	Generated file that contains DQ/DQS I/O atoms interconnects and instance. Arria II GX devices only.
<variation_name>_phy_alt_mem_phy_dq_dqs_clearbox.txt	Specification file that generates the <variation_name>_alt_mem_phy_dq_dqs file using the clearbox flow. Arria II GX devices only.
<variation_name>_phy_alt_mem_phy_pll.qip	Quartus II IP file for the PLL that your ALTMEMPHY variation uses that contains the files associated with this megafunction.
<variation_name>_phy_alt_mem_phy_pll.v/.vhd	The PLL megafunction file for your ALTMEMPHY variation, generated based on the language you chose in the MegaWizard Plug-In Manager.
<variation_name>_phy_alt_mem_phy_pll_bb.v/.cmp	Black box file for the PLL used in your ALTMEMPHY variation. Typically unused.
<variation_name>_phy_alt_mem_phy_reconfig.qip	Quartus II IP file for the PLL reconfiguration block. Only generated when targeting Arria GX, Arria II GX, HardCopy II, Stratix II, and Stratix II GX devices.
<variation_name>_phy_alt_mem_phy_reconfig.v/.vhd	PLL reconfiguration block module. Only generated when targeting Arria GX, Arria II GX, HardCopy II, Stratix II, and Stratix II GX devices.
<variation_name>_phy_alt_mem_phy_reconfig_bb.v/cmp	Blackbox file for the PLL reconfiguration block. Only generated when targeting Arria GX, Arria II GX, HardCopy II, Stratix II, and Stratix II GX devices.
<variation_name>_phy_alt_mem_phy_seq.vhd	Contains the sequencer used during calibration. This file is encrypted and is always in VHDL language regardless of the language you chose in the MegaWizard Plug-In Manager.
<variation_name>_phy_alt_mem_phy_seq_wrapper.v/.vhd	A wrapper file, for compilation only, that calls the sequencer file, created based on the language you chose in the MegaWizard Plug-In Manager.
<variation_name>_phy_alt_mem_phy_seq_wrapper.vo/.vho	A wrapper file, for simulation only, that calls the sequencer file, created based on the language you chose in the MegaWizard Plug-In Manager.
<variation_name>_phy_alt_mem_phy.v	Contains all modules of the ALTMEMPHY variation except for the sequencer. This file is always in Verilog HDL language regardless of the language you chose in the MegaWizard Plug-In Manager. The DDR3 SDRAM sequencer is included in the <variation_name>_alt_mem_phy.vhd file.
<variation_name>_phy_bb.v/.cmp	Black box file for your ALTMEMPHY variation, depending whether you are using Verilog HDL or VHDL language.
<variation_name>_phy_ddr_pins.tcl	Contains procedures used in the <variation_name>_report_timing.tcl file.
<variation_name>_phy_ddr_timing.sdc	Contains timing constraints for your ALTMEMPHY variation.

Table 2-2. Generated Files (Part 3 of 3)

Filename	Description
<variation_name>_phy_report_timing.tcl	Script that reports timing for your ALTMEMPHY variation during compilation.
<variation_name>_pin_assignments.tcl	Contains I/O standard, drive strength, output enable grouping, and termination assignments for your ALTMEMPHY variation. If your top-level design pin names do not match the default pin names or a prefixed version, edit the assignments in this file.

9. Set the <variation name>_example_top.v or .vhd file to be the project top-level design file.
 - a. On the File menu, click **Open**.
 - b. Browse to <variation name>_example_top and click **Open**.
 - c. On the Project menu, click **Set as Top-Level Entity**.
10. Simulate the example design (refer to “[Simulate the Example Design](#)” on [page 2-8](#)) and compile (refer to “[Compile the Design](#)” on [page 2-13](#)).

Simulate the Example Design

You can simulate the example design with the MegaWizard Plug-In Manager-generated IP functional simulation models. The MegaWizard Plug-In Manager generates a VHDL or Verilog HDL testbench for your example design and a simulation model of the memory you are targeting, which are in the **testbench** directory in your project directory.

You can use the IP functional simulation model with any Altera-supported VHDL or Verilog HDL simulator.

You can perform a simulation in a third-party simulation tool from within the Quartus II software, using NativeLink.




For more information on NativeLink, refer to the [Simulating Altera IP Using NativeLink](#) chapter in volume 3 of the *Quartus II Handbook*.

Simulating Using NativeLink


To set up simulation in the Quartus II software using NativeLink, follow these steps:

1. Create a custom variation with an IP functional simulation model, refer to step 4 in the “[Specify Parameters](#)” section on [page 2-2](#).
2. Set the top-level entity to the example project.
 - a. On the File menu, click **Open**.
 - b. Browse to <variation name>_example_top and click **Open**.
 - c. On the Project menu, click **Set as Top-Level Entity**.

3. Set up the Quartus II NativeLink.
 - a. On the Assignments menu, click **Settings**. In the **Category** list, expand **EDA Tool Settings** and click **Simulation**.
 - b. From the **Tool name** list, click on your preferred simulator.

 Check that the absolute path to your third-party simulator executable is set. On the Tools menu, click **Options** and select **EDA Tools Options**.

 - c. In **NativeLink settings**, select **Compile test bench** and click **Test Benches**.
 - d. Click **New** at the **Test Benches** page to create a testbench.
4. In the **New Test Bench Settings** dialog box, do the following:
 - a. Enter a name for the **Test bench name**.
 - b. In **Top level module in test bench**, enter the name of the automatically generated testbench, `<variation name>_example_top_tb`.
 - c. In **Design instance in test bench**, enter the name of the top-level instance, `dut`.
 - d. Under **Simulation period**, set **End simulation at** to 600 μ s.
 - e. Add the testbench files and automatically-generated memory model files. In the **File name** field, browse to the location of the memory model and the testbench, click **Open** and then click **Add**. The testbench is `<variation name>_example_top_tb.v`; memory model is `<variation name>_mem_model.v`.

 The auto generated generic SDRAM model may be used as a placeholder for a specific memory vendor supplied model. For information on how to replace the generic model with a vendor specific model, refer to “Perform RTL/Functional Simulation (Optional)” in *AN 436: Using DDR3 SDRAM in Stratix III and Stratix IV Devices*.

 - f. Select the files and click **OK**.
5. On the Processing menu, point to **Start** and click **Start Analysis & Elaboration** to start analysis.
6. On the Tools menu, point to **Run EDA Simulation Tool** and click **EDA RTL Simulation**.

IP Functional Simulations

For VHDL simulations with IP functional simulation models, perform the following steps:

1. Create a directory in the `<project directory>\testbench` directory.

2. Launch your simulation tool from this directory and create the following libraries:
 - altera_mf
 - lpm
 - sgate
 - *<device name>*
 - altera
 - ALTGXB
 - *<device name>*_hssi
 - auk_ddr3_hp_user_lib
3. Compile the files into the appropriate library (AFI mode) as shown in [Table 2-3](#). The files are in VHDL93 format.

Table 2-3. Files to Compile—VHDL IP Functional Simulation Models (Part 1 of 2)

Library	File Name
altera_mf	<i><QUARTUS_ROOTDIR>/eda/sim_lib/altera_mf_components.vhd</i> <i><QUARTUS_ROOTDIR>/eda/sim_lib/altera_mf.vhd</i>
lpm	<i>/eda/sim_lib/220pack.vhd</i> <i>/eda/sim_lib/220model.vhd</i>
sgate	<i>eda/sim_lib/sgate_pack.vhd</i> <i>eda/sim_lib/sgate.vhd</i>
<i><device name></i>	<i>eda/sim_lib/<device name>_atoms.vhd</i> <i>eda/sim_lib/<device name>_components.vhd</i> <i>eda/sim_lib/<device name>_hssi_atoms.vhd (1)</i>
altera	<i>eda/sim_lib/altera_primitives_components.vhd</i> <i>eda/sim_lib/altera_primitives.vhd</i>
ALTGXB (1)	<i><device name>_mf.vhd</i> <i><device name>_mf_components.vhd</i>
<i><device name></i> _hssi (1)	<i><device name>_hssi_components.vhd</i> <i><device name>_hssi_atoms.vhd</i>

Table 2-3. Files to Compile—VHDL IP Functional Simulation Models (Part 2 of 2)

Library	File Name
auk_ddr3_hp_user_lib	<QUARTUS_ROOTDIR>/ libraries/vhdl/altera/altera_europa_support_lib.vhd
	<project directory>/<variation name>_phy_alt_mem_phy_delay.vhd
	<project directory>/<variation name>_phy_alt_mem_phy_seq_wrapper.vho
	<project directory>/<variation name>_auk_ddr3_hp_controller_wrapper.vho
	<project directory>/<variation name>_phy.vho
	<project directory>/<variation name>.vhd
	<project directory>/<variation name>_example_top.vhd
	<project directory>/<variation name>_controller_phy.vhd
	<project directory>/<variation name>_phy_alt_mem_phy_pll.vhd
	<project directory>/<variation name>_phy_alt_mem_phy_seq.vhd
	<project directory>/<variation name>_example_driver.vhd
	<project directory>/<variation name>_ex_lfsr8.vhd
	testbench/<variation name>_example_top_tb.vhd
	testbench/<variation name>_mem_model.vhd

Note for :

(1) Applicable only for Stratix IV devices.



If you are targeting Stratix IV devices, you need both the Stratix IV and Stratix III files (**stratixiv_atoms** and **stratixiii_atoms**) to simulate in your simulator, unless you are using NativeLink.

4. Load the testbench in your simulator with the timestep set to picoseconds.

For Verilog HDL simulations with IP functional simulation models, follow these steps:

1. Create a directory in the <project directory>\testbench directory.
2. Launch your simulation tool from this directory and create the following libraries:
 - altera_mf_ver
 - lpm_ver
 - sgate_ver
 - <device name>_ver
 - altera_ver
 - ALTGXB_ver
 - <device name>_hssi_ver
 - auk_ddr3_hp_user_lib
3. Compile the files into the appropriate library (AFI mode) as shown in [Table 2-4 on page 2-12](#).

Table 2-4. Files to Compile—Verilog HDL IP Functional Simulation Models

Library	File Name
altera_mf_ver	<QUARTUS_ROOTDIR>/eda/sim_lib/altera_mf.v
lpm_ver	/eda/sim_lib/220model.v
sgate_ver	eda/sim_lib/sgate.v
<device name>_ver	eda/sim_lib/<device name>_atoms.v eda/sim_lib/<device name>_hssi_atoms.v (1)
altera_ver	eda/sim_lib/altera_primitives.v
ALTGXB_ver (1)	<device name>_mf.v
<device name>_hssi_ver (1)	<device name>_hssi_atoms.v
auk_ddr3_hp_user_lib	alt_mem_phy_defines.v
	<project directory>/<variation name>_phy_alt_mem_phy_seq_wrapper.vo
	<project directory>/<variation name>_auk_ddr3_hp_controller_wrapper.vo
	<project directory>/<variation name>.v
	<project directory>/<variation name>_example_top.v
	<project directory>/<variation name>_phy.v
	<project directory>/<variation name>_controller_phy.v
	<project directory>/<variation name>_phy_alt_mem_phy_pll.v
	<project directory>/<variation name>_phy_alt_mem_phy.v
	<project directory>/<variation name>_example_driver.v
	<project directory>/<variation name>_ex_lfsr8.v
	testbench/<variation name>_example_top_tb.v
	testbench/<variation name>_mem_model.v

Notes for :

(1) Applicable only for Stratix IV devices.



If you are targeting Stratix IV devices, you need both the Stratix IV and Stratix III files (**stratixiv_atoms** and **stratixiii_atoms**) to simulate in your simulator, unless you are using NativeLink.

4. Configure your simulator to use transport delays, a timestep of picoseconds, and to include all the libraries in [Table 2-4](#).

Compile the Design

To use the Quartus II software to compile your design and perform post-compilation timing analysis, follow these steps:

1. Set up the TimeQuest timing analyzer.
 - a. On the Assignments menu, click **Timing Analysis Settings**, select **Use TimeQuest Timing Analyzer during compilation**, and click **OK**.
 - b. Add the Synopsys Design Constraints (.sdc) files, *<variation name>_phy_dds_timing.sdc*, to your project. On the Project menu, click **Add/Remove Files in Project** and browse to select the file.
 - c. Add the .sdc file for the example top-level design, *<variation name>_example_top.sdc*, to your project. This file is only required if you are using the example as the top level design.
2. Use one of the following procedures to specify I/O standard assignments for pins:
 - If you have a single DDR3 SDRAM interface, and your top-level pins have default naming shown in the example design, run *<variation name>_pin_assignments.tcl*.
 - If your design contains pin names that do not match the design, edit the *<variation name>_pin_assignments.tcl* file before you run the script. Follow these steps:
 - a. Open *<variation name>_pin_assignments.tcl* file.
 - b. Based on the flow you are using, set the *sopc_mode* value to Yes or No.
 - SOPC Builder System flow:


```
if {[info exists socp_mode]} {set socp_mode YES}
```
 - MegaWizard Plug-In Manager flow:


```
if {[info exists socp_mode]} {set socp_mode NO}
```
 - c. Type your preferred prefix in the *pin_prefix* variable. For example, to add the prefix *my_mem*, do the following:


```
if {[info exists set_prefix]}{set pin_prefix "my_mem_"}
```


After setting the prefix, the pin names are expanded as shown in the following:

 - SOPC Builder System flow:


```
my_mem_cs_n_from_the_<your instance name>
```
 - MegaWizard Plug-In Manager flow:


```
my_mem_cs_n[0]
```

3. Set the top-level entity to the top-level design.
 - a. On the File menu, click **Open**.
 - b. Browse to your SOPC Builder system top-level design or *<variation name>_example_top* if you are using MegaWizard Plug-In Manager, and click **Open**.
 - c. On the Project menu, click **Set as Top-Level Entity**. Browse to *<variation name>_example_top* and click **Open**.
 - d. On the Project menu, click **Set as Top-Level Entity**.
4. Assign the pin locations to the pins in your design.
 - Use either the Pin Planner or Assignment Editor to assign the clock source pin manually. Also choose which DQS pin groups should be used by assigning each DQS pin to the required pin. The Quartus II Fitter then automatically places the respective DQ signals onto suitable DQ pins within each group.
or
 - Manually specify all DQ and DQS pins to align your project with your PCB requirements.
or
 - Manually specify all project pin locations to align your project with your PCB requirements.

 When assigning pins, ensure that you set an appropriate I/O standard for the non-memory interfaces, such as the clock source and the reset inputs. For example, for DDR3 SDRAM, select **1.5 V**. Also select in which bank or side of the device you want the Quartus II software to place them.
5. For Stratix III and Stratix IV designs, if you are using advanced I/O timing, specify board trace models in the **Device & Pin Options** dialog box. If you are using any other device and not using advanced I/O timing, specify the output pin loading for all memory interface pins.
6. Select your required I/O driver strength (derived from your board simulation) to ensure that you correctly drive each signal or ODT setting and do not suffer from overshoot or undershoot.
7. To compile the design, on the Processing menu, click **Start Compilation**.

Program Device and Implement the Design

After you compile the example design, you can perform RTL simulation (refer to [“Simulate the Example Design” on page 2-8](#)) or program your targeted Altera device to verify the example design in hardware.

To implement your design based on the example design, replace the example driver in the example design with your own logic.

Memory Settings

The **Memory Settings** page provides the same options as the **ALTMEMPHY** megafunction **Memory Settings** page.



For more information on the memory settings, refer to the *External Memory PHY Interface Megafunction User Guide (ALTMEMPHY)*.

PHY Settings

Board skew is the skew across all the memory interface signals, which includes clock, address, command, data, mask, and strobe signals.



For more information on the PHY settings, refer to the *External Memory PHY Interface Megafunction User Guide (ALTMEMPHY)*.

Controller Settings

Table 3–1 shows the options provided in the **Controller Settings** page.

Table 3–1. Controller Settings

Parameter	Range	Description
Enable error detection and correction logic	On or off	Turn on to add the optional ECC to the design, refer to “Error Correction Coding (ECC)” on page 4–6.
Enable user auto-refresh controls	On or off	Turn on for user control of the refreshes, refer to “User Refresh Control” on page 4–16.
Enable auto-precharge control	On or off	Turn on if you need fast random access, refer to “Auto-Precharge Commands” on page 4–18
Enable power down controls	On or off	Turn on to enable the controller to allow you to place the external memory device in a power-down mode, refer to “Self-Refresh and Power-Down Commands” on page 4–17
Enable self-refresh controls	On or off	Turn on to enable the controller to allow you to place the external memory device in a self-refresh mode, refer to “Self-Refresh and Power-Down Commands” on page 4–17
Local Interface Protocol	Native or Avalon Memory-Mapped	Specifies the local side interface between the user logic and the memory controller. The Avalon-MM interface allows you to easily connect to other Avalon-MM peripherals.

The DDR3 SDRAM High-Performance Controller MegaCore function instantiates encrypted control logic and the ALTMEMPHY megafunction. The controller accepts read and write requests from the user on its local interface, using either the Avalon-MM interface protocol or the native interface protocol. It converts these requests into the necessary SDRAM commands, including any required bank management commands. Each read or write request on the Avalon-MM or native interface maps to one SDRAM read or write command. The DDR3 controller operates in half-rate mode and accepts requests of size 1 or 2 on the local interface.

If you request a burst size of 1, the controller issues a memory burst of 4 using the DDR3 on-the-fly burst chop (waits for two cycles before issuing the next read or write command). If you request a burst size of 2, the controller issues a memory burst of 8 (issues the next read or write command back to back). Requests of size 2 on the local interface produce better throughput because DDR3 memories cannot accept back to back bursts of size 4.

The bank management logic in the controller keeps a row open in every bank in the memory system. For example, a controller configured for a dual-rank, 8-bank DDR3 SDRAM DIMM keeps an open row in each of the 16 banks. The controller allows you to request an auto-precharge read or auto-precharge write, allowing control over whether to keep that row open after the request. Maximum efficiency can be achieved by issuing reads and writes to the same bank, with the last access to that bank being an auto-precharge read or write. The controller does not do any access reordering.



For more information on the ALTMEMPHY megafunction, refer to the *External Memory PHY Interface Megafunction User Guide (ALTMEMPHY)*.

Block Description

Figure 4–1 on page 4–1 shows a block diagram of the DDR3 SDRAM high-performance controller.

Figure 4–1. DDR3 SDRAM High-Performance Controller Block Diagram

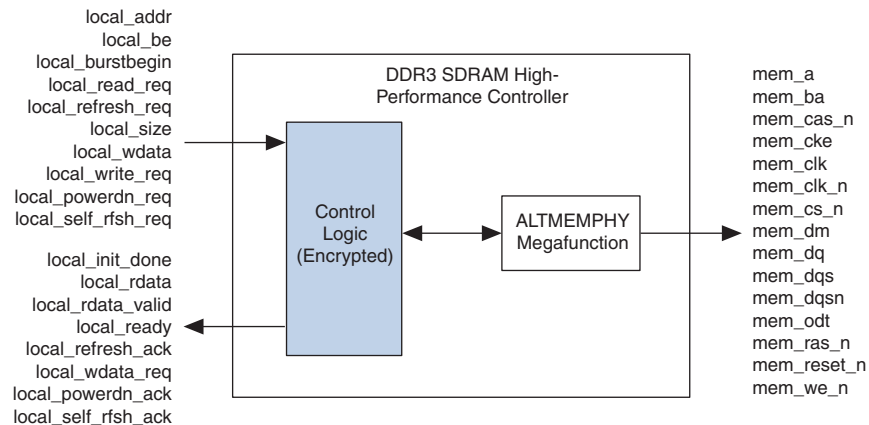
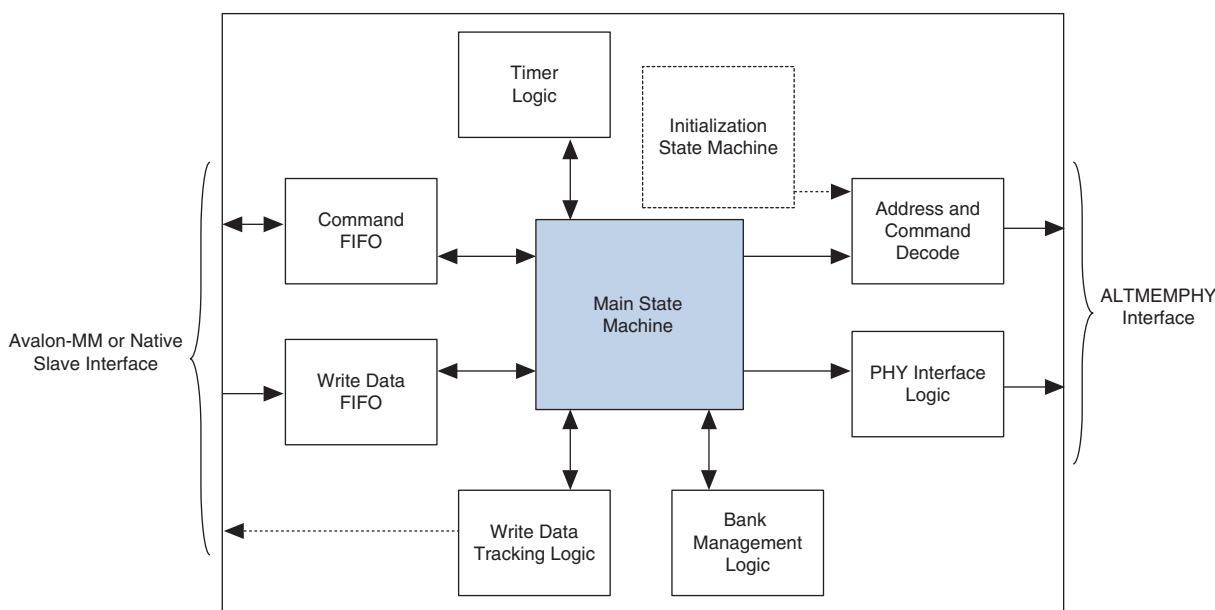


Figure 4–2 shows a block diagram of the DDR3 SDRAM high-performance controller architecture.

Figure 4–2. DDR3 SDRAM High-Performance Controller Architecture Block Diagram



The blocks in Figure 4–2 are described in the following sections.

Command FIFO

This FIFO allows the controller to buffer up to four consecutive read or write commands. It is built from logic elements, and stores the address, read or write flag, and burst count information. If this FIFO fills up, the `local_ready` signal to the user is deasserted until the main state machine takes a command from the FIFO.

Write Data FIFO

The write data FIFO holds the write data from the user until the main state machine can send it to the ALTMEMPHY megafunction (which does not have a write data buffer). In Avalon-MM interface mode, the user logic presents a write request, address, burst count, and one or more beats of data. The write data beats are placed into the FIFO until they are needed. In native interface mode, the user logic presents a write request, address, and burst count. The controller then requests the correct number of write data beats from the user via the `local_wdata_req` signal and the user logic must return the write data in the clock cycle after the write data request signal.

This FIFO is sized to be deeper than the command FIFO to prevent it from filling up and interrupting streaming writes.

Write Data Tracking Logic

This logic keeps track of how many beats of write data are in the FIFO. In native interface mode, this logic manages how much more data to request from the user logic and issues the `local_wdata_req` signal.

Main State Machine

This state machine decides what DDR commands to issue based on inputs from the command FIFO, the bank management logic, and the timer logic.

Bank Management Logic

The bank management logic keeps track the current state of each bank. It can keep a row open in every bank in your memory system. The state machine uses the information provided by this logic to decide whether it needs to issue bank management commands before it reads or writes to the bank. The controller always leaves the bank open unless the user requests an auto-precharge read or write. The periodic refresh process also causes all the banks to be closed.

Timer Logic

The timer logic tracks whether the required minimum number of clock cycles has passed since the last relevant command was issued. For example, the timer logic records how many cycles have elapsed since the last activate command so that the state machine knows it is safe to issue a read or write command (t_{RCD}). The timer logic also counts the number of clock cycles since the last periodic refresh command and sends a high priority alert to the state machine if the number of clock cycles has expired.

Initialization State Machine

The initialization state machine issues the appropriate sequence of command to initialize the memory devices. It is specific to DDR3 as each memory type requires a different sequence of initialization commands.

If the ALTMEMPHY megafunction is in AFI mode, then the megafunction is responsible for initializing the memory. In this case, the controller does not have the initialization state machine.

Address and Command Decode

When the state machine wants to issue a command to the memory, it asserts a set of internal signals. The address and command decode logic turns these into the DDR-specific RAS/CAS/WE commands.

PHY Interface Logic

When the main state machine issues a write command to the memory, the write data for that write burst has to be fetched from the write data FIFO. The relationship between write command and write data depends on the memory type, ALTMEMPHY interface type, CAS latency, and the full-rate or half-rate setting. The PHY interface logic adjusts the timing of the write data FIFO read request signal so that the data arrives on the external memory interface DQ pins at the correct time.

ODT Generation Logic

The ODT generation logic (not shown) calculates when and for how long to enable the ODT outputs. It also decides which ODT bit to enable, based on the number of chip selects in the system.

- 1 DIMM (1 or 2 Chip Selects)

In the case of a single DIMM, the ODT signal is only asserted during writes. The ODT signal on the DIMM at `mem_cs[0]` is always used, even if the write command on the bus is to `mem_cs[1]`. In other words, `mem_odt[0]` is always asserted even if there are two ODT signals.

- 2 or more DIMMs

In the multiple DIMM case, the appropriate ODT bit is asserted for both read and writes. The ODT signal on the adjacent DIMM is enabled as shown.

If a write/read is happening to:

ODT enabled:

<code>mem_cs[0]</code> or <code>cs[1]</code>	<code>mem_odt[2]</code>
<code>mem_cs[2]</code> or <code>cs[3]</code>	<code>mem_odt[0]</code>
<code>mem_cs[4]</code> or <code>cs[5]</code>	<code>mem_odt[6]</code>
<code>mem_cs[6]</code> or <code>cs[7]</code>	<code>mem_odt[4]</code>

Low Power Mode Logic

The low power mode logic (not shown) monitors the `local_powerdn_req` and `local_self_rfsh_req` request signals. This logic also informs the user of the current low power state via that `local_powerdn_ack` and `local_self_rfsh_ack` acknowledge signals.

Control Logic

Bus commands control SDRAM devices using combinations of the `mem_ras_n`, `mem_cas_n`, and `mem_we_n` signals. For example, on a clock cycle where all three signals are high, the associated command is a no operation (NOP). A NOP command is also indicated when the chip select signal is not asserted. Table 4-1 shows the standard SDRAM bus commands.

Table 4-1. Bus Commands

Command	Acronym	<code>ras_n</code>	<code>cas_n</code>	<code>we_n</code>
No operation	NOP	High	High	High
Active	ACT	Low	High	High
Read	RD	High	Low	High
Write	WR	High	Low	Low
Precharge	PCH	Low	High	Low
Auto refresh	ARF	Low	Low	High
Load mode register	LMR	Low	Low	Low

The DDR3 SDRAM high-performance controller must open SDRAM banks before they access addresses in that bank. The row and bank to be opened are registered at the same time as the active (ACT) command. The DDR3 SDRAM high-performance controller closes the bank and opens the bank again if it needs to access a different row. The precharge (PCH) command closes only a bank.

The primary commands used to access SDRAM are read (RD) and write (WR). When the WR command is issued, the initial column address and data word is registered. When a RD command is issued, the initial address is registered. The initial data appears on the data bus 5 to 11 clock cycles later. This delay is the column address strobe (CAS) latency and is due to the time required to read the internal DRAM core and register the data on the bus. The CAS latency (of 6) depends on the speed of the SDRAM and the frequency of the memory clock. In general, the faster the clock, the more cycles of CAS latency are required. After the initial RD or WR command, sequential reads and writes continue until the burst length is reached. DDR3 SDRAM devices support fixed burst lengths of 4 or 8 data cycles or a the on-the-fly mode where the controller can request a burst of 4 or 8 for each read or write command. This on-the-fly mode is the only mode supported. The auto-refresh command (ARF) is issued periodically to ensure data retention. This function is performed by the DDR3 SDRAM high-performance controller.

The load mode register command (LMR) configures the SDRAM mode register. This register stores the CAS latency, burst length, and burst type.



For more information, refer to the specification of the SDRAM that you are using.

Latency

There are two types of latency that you must consider for memory controller designs—read and write latencies. We define the read and write latencies as follows.

- Read latency is the time it takes for the read data to appear at the local interface after you initiate the read request signal to the controller.
- Write latency is the time it takes for the write data to appear at the memory interface after you initiate the write request signal to the controller.

Latency calculations are made with the following assumptions:

- Reading and writing to the rows that are already open
- The local_ready signal is asserted high (no wait states)
- No refresh cycles occur before transaction
- The latency is defined using the local side frequency and absolute time (ns)



For the half rate controller, the local side frequency is half the memory interface frequency.

Altera defines the read and write latencies in terms of the local interface clock frequency and by the absolute time for the memory controllers.

Table 4–2 shows the read and write latency derived from the write and read latency definitions for half rate controllers, and for Stratix III and Stratix IV devices.

Table 4–2. Typical Latency

Device	Controller Rate	Frequency (MHz)	Latency Type	Total Latency	
				Local Clock Cycles	Time (ns)
Stratix III	Half	400	Read	23	115
			Write	14	68
Stratix IV	Half	400	Read	23	115
			Write	14	68



The exact latency depends on your precise configuration. You should obtain precise latency from simulation, but this figure may vary in hardware because of the automatic calibration process.

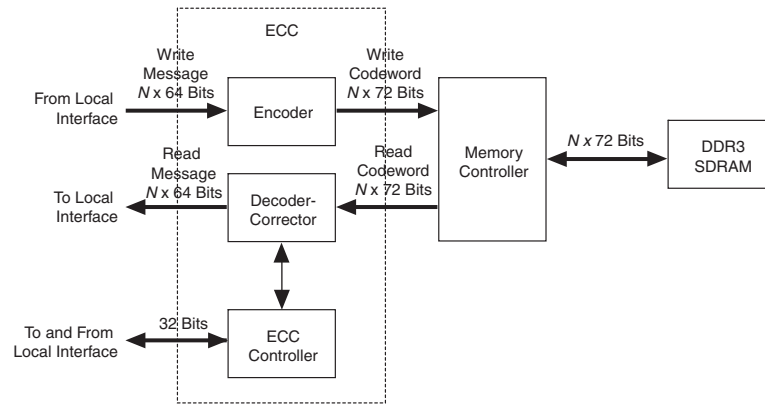
Error Correction Coding (ECC)

The ECC comprises an encoder and a decoder-corrector, which can detect and correct single-bit errors and detect double-bit errors. The ECC uses an 8-bit ECC for each 64-bit message. The ECC has the following features:

- Hamming code ECC that encodes every 64-bits of data into 72-bits of codeword with 8-bits of Hamming code parity bits
- Latency:
 - Maximum of 1 or 2 clock delay during writes
 - Minimum 1 or 3 clock delay during reads
- Detects and corrects all single-bit errors. Also the ECC sends an interrupt when the user-defined threshold for a single-bit error is reached.
- Detects all double-bit errors. Also, the ECC counts the number of double-bit errors and sends an interrupt when the user-define threshold for double-bit error is reached.
- Accepts partial writes
- Creates forced errors to check the functioning of the ECC
- Powers up in a sensible state

Figure 4–3 shows the ECC block diagram

Figure 4–3. ECC Block Diagram



The ECC comprises the following blocks:

- The encoder—encodes the 64-bit message to a 72-bit codeword
- The decoder-corrector—decodes and corrects the 72-bit codeword if possible
- The ECC controller—controls multiple encoder and decoder-correctors, so that the ECC can handle different bus widths. Also, it controls the following functions of the encoder and decoder-corrector:
 - Interrupts:
 - Detected and corrected single-bit error
 - Detected double-bit error
 - Single-bit error counter threshold exceeded
 - Double-bit error counter threshold exceeded
 - Configuration registers:
 - Single-bit error detection counter threshold
 - Double-bit error detection counter threshold
 - Capture status for first encountered error or most recent error
 - Enable deliberate corruption of ECC for test purposes.
 - Status registers:
 - Error address
 - Error type: single-bit error or double-bit error
 - Respective byte error ECC syndrome
- Error signal—an error signal corresponding to the data word is provided with the data and goes high if a double-bit error that cannot be corrected occurs in the return data word.

- Counters:
 - Detected and/or corrected single-bit errors
 - Detected double-bit errors



For more information on the ECC registers, refer to [Appendix A, ECC Register Description](#).

The ECC can instantiate multiple encoders, each running in parallel, to encode any width of data words assuming they are integer multiples of 64.

The ECC operates between the local (native or Avalon-MM interface) and the memory controller.

The ECC has an $N \times 64$ -bit (where N is an integer) wide interface, between the local interface and the ECC, for receiving and returning data from the local interface. This interface can be a native interface or an Avalon-MM slave interface, you select the type of interface in the MegaWizard interface.

The ECC has a second interface between the local interface and the ECC, which is a 32-bit wide Avalon-MM slave to control and report the status of the operation of the ECC controller.

The encoded data from the ECC is sent to the memory controller using a $N \times 72$ -bit wide Avalon-MM master interface, which is between the ECC and the memory controller.

When testing the DDR3 SDRAM high-performance controller, you can turn off the ECC.

Interrupts

The ECC issues an interrupt signal when one of the following scenarios occurs:

- The single-bit error counter reaches the set maximum single-bit error threshold value.
- The double-bit error counter reaches the set maximum double-bit error threshold value.

The error counters increment every time the respective event occurs for all N parts of the return data word. This incremented value is compared with the maximum threshold and an interrupt signal is sent when the value is equal to the maximum threshold. The ECC clears the interrupts when you write a 1 to the respective status register. You can mask the interrupts from either of the counters using the control word.

Partial Writes

The ECC supports partial writes. Along with the address, data, and burst signals, the Avalon-MM interface also supports a signal vector that is responsible for byte-enable. Every bit of this signal vector represents a byte on the data-bus. Thus, a 0 on any of these bits is a signal for the controller not to write to that particular location—a partial write. For partial writes, the ECC performs the following steps:

- Stalls further read or write commands from the Avalon-MM interface when it receives a partial write condition.

- Simultaneously sends a self-generated read command, for the partial write address, to the memory controller.
- Upon receiving a return data from the memory controller for the particular address, the ECC decodes the data, checks for errors, and then sends it to the ECC controller.
- The ECC controller merges the corrected or correct dataword with the incoming information.
- Sends the updated dataword to the encoder for encoding and then sends to the memory controller with a write command.
- Releases the stall of commands from the Avalon-MM interface, which allows it to receive new commands.

The following corner cases can occur:

- A single-bit error during the read phase of the read-modify-write process. In this case, the single-bit error is corrected first, the single-bit error counter is incremented and then a partial write is performed to this corrected decoded data word.
- A double-bit error during the read phase of the read-modify-write process. In this case, the double-bit error counter is incremented and an interrupt is sent through the Avalon-MM interface. The new write word is not written to its location. A separate field in the interrupt status register highlights this condition.

Partial Bursts

Some DIMMs do not have the DM pins and so do not support partial bursts. A minimum of four words must be written to the memory at the same time. In cases of partial burst write, the ECC offers a mechanism similar to the partial write.

In cases of partial bursts, the write data from the native interface is stored in a 64-bit wide FIFO buffer of maximum burst size depth, while in parallel a read command of the corresponding addresses is sent to the DIMM. Further commands from native interface are stalled until the current burst is read, modified, and written back to the memory controller.

ECC Latency

Using the ECC results in the following latency changes:

- For a local burst length of 1, the write latency increases by one clock cycle; the read latency increases by one clock cycle (including checking and correction).
- A partial write results in a read followed by write in the ECC controller, so latency depends on the time the controller takes to fetch the data from the particular address.
- For a single-bit error, the automatic correction of memory takes place without stalling the read cycle (if enabled), which stalls further commands to the ECC controller, while the correction takes place.

Example Design

The MegaWizard Plug-In Manager helps you create an example design that shows you how to instantiate and connect the DDR3 SDRAM high-performance controller. The example design consists of the DDR3 SDRAM high-performance controller and some driver logic to issue read and write requests to the controller. The example design is a working system that you can compile and use for both static timing checks and board tests.

Figure 4-4 shows the testbench and the example design.

Figure 4-4. Testbench & Example Design

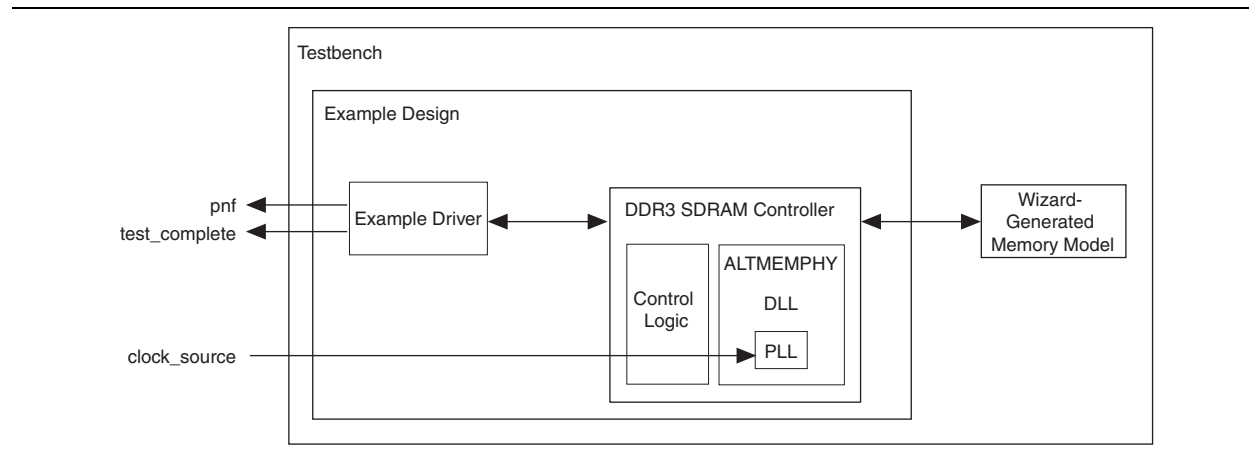


Table 4-3 describes the files that are associated with the example design and the testbench.

Table 4-3. Example Design & Testbench Files

Filename	Description
<variation name>_example_top_tb.v or .vhd	Testbench for the example design.
<variation name>_example_top.v or .vhd	Example design.
<variation name>_example_driver.v or .vhd	Example driver.
<variation name>_mem_model.v or .vhd	Wizard-generated memory model.
<variation name>.v or .vhd	Top-level description of the custom MegaCore function.
<variation name>.qip	Contains Quartus II project information for your MegaCore function variations.

Example Driver

The example driver is a self-checking test pattern generator for the memory interface. It uses a state machine to write and read from the memory to verify that the interface is operating correctly.

It performs the following tests and loops back the tests indefinitely:

- Sequential addressing writes and reads

The state machine writes pseudo-random data generated by a linear feedback shift register (LFSR) to a set of incrementing row, bank, and column addresses. The state machine then resets the LFSR, reads back the same set of addresses, and compares the data it receives against the expected data. You can adjust the length and pattern of the bursts that are written by changing the MAX_ROW, MAX_BANK, and MAX_COL constants in the example driver source code, and the entire memory space can be tested by adjusting these values. You can skip this test by setting the test_seq_addr_on signal to logic zero.

- Incomplete write operation

The state machine issues a series of write requests that are less than the maximum burst size supported by your controller variation. The addresses are then read back to ensure that the controller has issued the correct signals to the memory. This test is only applicable in full-rate mode or in DDR3 half-rate mode, when the local burst size is two. You can skip this test by setting the test_incomplete_writes_on signal to logic zero.

- Byte enable/data mask pin operation

The state machine issues two sets of write commands, the first of which clears a range of addresses. The second set of write commands has only one byte enable bit asserted. The state machine then issues a read request to the same addresses and the data is verified. This test checks if the data mask pins are operating correctly. You can skip this test by setting the test_dm_pin_on signal to logic zero.

- Address pin operation

The example driver generates a series of write and read requests starting with an all-zeros pattern, a walking-one pattern, a walking-zero pattern, and ending with an all-zeros pattern. This test checks to make sure that all the individual address bits are operating correctly. You can skip this test by setting the test_addr_pin_on signal to logic zero.

- Low-power mode operation

The example driver requests the controller to place the memory into power-down and self-refresh states, and hold it in those states for the amount of time specified by the COUNTER_VALUE signal. You can vary this value to adjust the duration the memory is kept in the low-power states. This test is only available if your controller variation enables the low-power mode option.

The example driver has four outputs that allow you to observe which tests are currently running and if the tests are passing. The pass not fail (pnf) signal goes low once one or more errors occur and remains low. The pass not fail per byte (pnf_per_byte) signal goes low when there is incorrect data in a byte but goes back high again once correct data is observed in the following byte. The test_status signal indicates the test that is currently running, allowing you to determine which test has failed. The test_complete signal goes high for a single clock cycle at the end of the set of tests.

Table 4-4 shows the bit mapping for each test status.

Table 4-4. Test Status[] Bit Mapping

Bit	Test
0	Sequential address test
1	Incomplete write test
2	Data mask pin test
3	Address pin test
4	Power-down test
5	Self-refresh test
6	Auto precharge test



For more details on how to run the simulation script, refer to “Simulate the Example Design” on page 2-8.

Interfaces & Signals

This section describes the following topics:

- “Interface Description” on page 4-12
- “Signals” on page 4-19

Interface Description

This section describes the following local-side interface requests:

- “Writes”
- “Reads” on page 4-14
- “User Refresh Control” on page 4-16
- “Self-Refresh and Power-Down Commands” on page 4-17
- “Auto-Precharge Commands” on page 4-18
- “Initialization Timing” on page 4-18

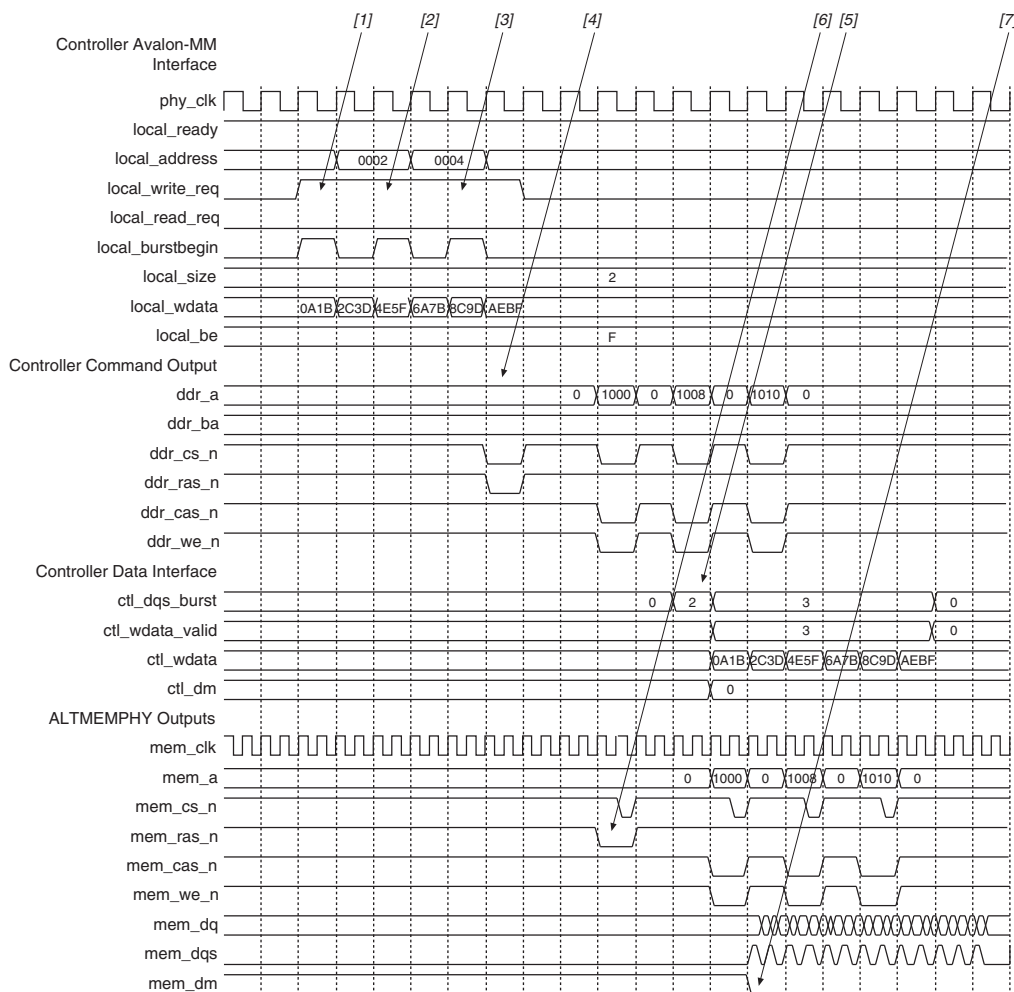


These interface requests are for the native interface. For the Avalon-MM interface, refer to the *Avalon Interface Specifications*.

Writes

Figure 4-5 on page 4-13 shows three back-to-back write requests of size 2, to sequential addresses. The DDR3 SDRAM controller supports the on-the-fly burst mode. This mode allows you to request bursts of length 1 or 2 on the local side interface (equivalent to 4 or 8 on the DDR3 SDRAM side interface).

Figure 4-5. Writes



The following sequence corresponds with the numbered items in Figure 4-5.

1. The user logic requests the first write, by asserting the `local_write_req`, `local_burstbegin`, size and address signals for this write. In this example, the request is a burst of length 2 (8 on the DDR3 SDRAM side) to address 0. The `local_ready` signal is asserted, which indicates that the controller has accepted this request, and the user logic can request another read or write in the following clock cycle. If the `local_ready` signal is not asserted, the user logic must keep the write request, size, and address signals asserted. For this burst of length 2, you must present the second beat of write data in the next clock cycle.



`local_be` is active high; `mem_dm` is active low.

To map `local_wdata` and `local_be` to `mem_dq` and `mem_dm`, consider the following full rate example with 32-bit `local_wdata` and 16-bit `mem_dq`.

```

local_wdata =          <22334455>          <667788AA>          <BBCCDDEE>
local_be  =              <1100>              <0110>              <1010>

```

These values map to:

```

mem_dq =          <4455>   <2233>   <88AA>   <6677>   <DDEE>   <BBCC>
mem_dm =          <1 1>    <0 0>    <0 1>    <1 0>    <0 1>    <0 1>

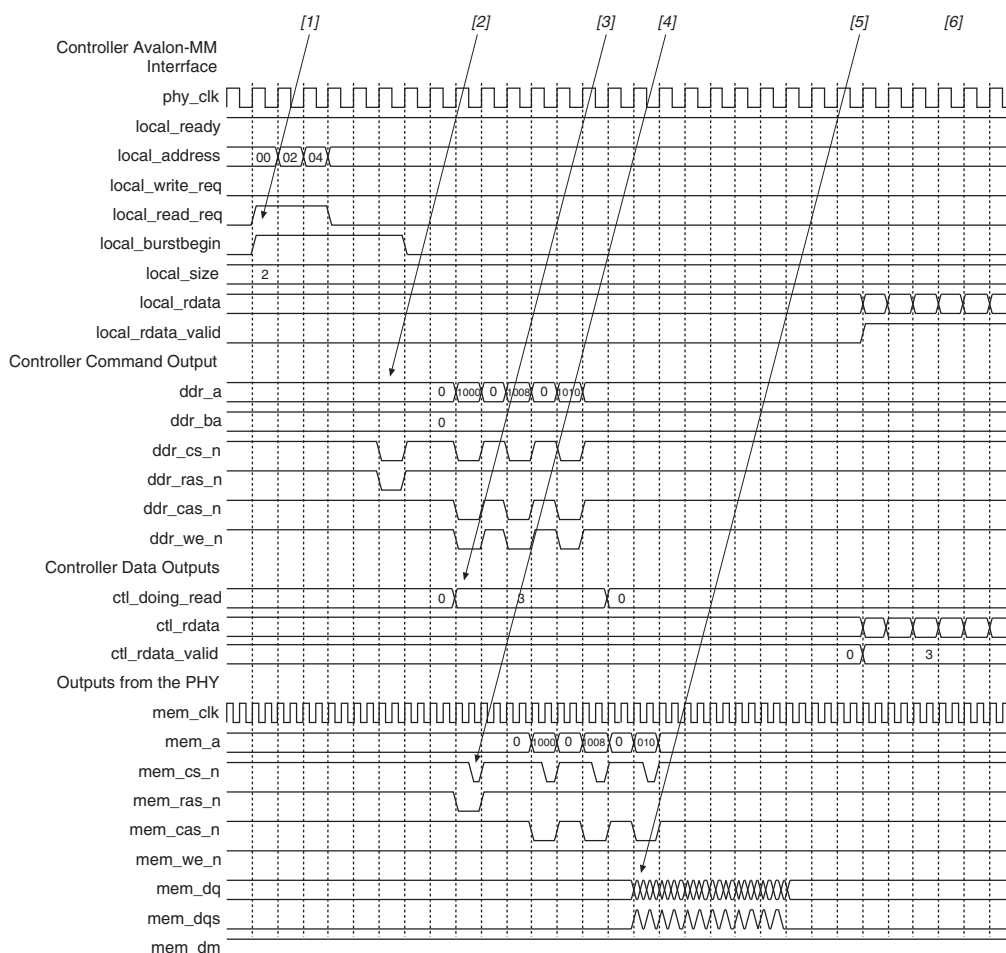
```

2. The user logic requests a second write to a sequential address, of size 2 (8 on the DDR3 SDRAM side). The `local_ready` signal remains asserted, which indicates that the controller has accepted the request.
3. The user logic requests the third write. The controller is able to buffer up to four requests so the `local_ready` signal stays high and the request is accepted.
4. The controller issues the necessary bank activation command and the three write commands sequentially to the ALTMEMPHY megafunction, which converts these commands from half-rate to full-rate and issues them to the memory device.
5. The controller asserts the signals that control how long the DQS (`ctl_dqs_burst`) and DQ (`ctl_wdata_valid`) outputs are enabled for. The `ctl_dqs_burst` and `ctl_wdata_valid` signals are two bits wide so that the controller can control how many full-rate `mem_clk` cycles the DQS and DQ signals are enabled for, even though the controller is operating on the half-rate clock. In this example, the DQS outputs are enabled for 13 full-rate clock cycles (to account for the DQS preamble) and the DQ is enabled for 12 full-rate clock cycles. The write data (`ctl_wdata`) and mask (`ctl_dm`) are issued at the same time as the `ctl_wdata_valid`.
6. The ALTMEMPHY megafunction issues the bank activation and write commands to the memory device.
7. The ALTMEMPHY megafunction issues the DQS, DQ and DM signals to write the data to the memory device.

Reads

Figure 4-6 on page 4-15 shows three read requests of size 2. The DDR3 SDRAM controller supports the on-the-fly burst mode. This mode allows you to request bursts of length 1 or 2 on the local side interface (equivalent to 4 or 8 on the DDR3 SDRAM side interface).

Figure 4-6. Reads



The following sequence corresponds with the numbered items in Figure 4-6.

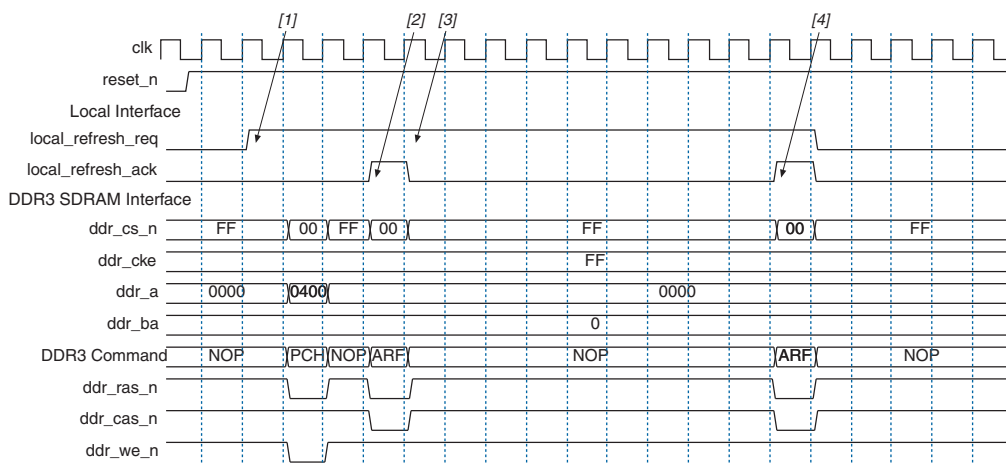
1. The user logic requests the three back-to-back reads of size 2 (8 on the DDR3 SDRAM side) by asserting the `local_read_req`, `local_burstbegin`, `local_size` and `local_address` signals for each read. The `local_ready` signal is asserted, which indicates that the controller has accepted each request, and the user logic can request another read or write in the following clock cycle. If the `local_ready` signal is not asserted, the user logic must keep the read request, size, and address signals asserted.
2. The controller issues the necessary bank activation command and the three read commands sequentially to the ALTMEMPHY megafunction, which converts these commands from half-rate to full-rate and issues them to the memory device.
3. The controller asserts the `ctl_doing_read` signals to indicate to the ALTMEMPHY megafunction when and for how long to enable to the capture registers.
4. The ALTMEMPHY megafunction issues the bank activation and read commands to the memory device.

5. The memory device returns the read data for the addresses requested after the CAS latency along with the DQS strobe signal that the ALTMEMPHY megafunction uses to capture the read data.
6. The controller issues the read data to the user logic, marking it valid with the `local_rdata_valid` signal. The for the subsequent read requests. The exact number of clock cycles between the controller accepting the request and returning the data depends on the number of other requests pending in the controller, the state the memory is in, and the timing requirements of the memory (for example, the CAS latency).

User Refresh Control

Figure 4-7 shows the user refresh control interface. This feature allows you to control when the controller issues refreshes to the memory. This feature allows better control of worst case latency and allows refreshes to be issued in bursts to take advantage of idle periods.

Figure 4-7. User Refresh Control



Note to Figure 4-7:

(1) DDR3 Command shows the command that the command signals are issuing.

The following sequence corresponds with the numbered items in Figure 4-7.

1. The user logic asserts the refresh request signal to indicate to the controller that it should perform a refresh. The state of the read and write requests signal does not matter as the controller gives priority to the refresh request (although it completes any currently active reads or writes).
2. The controller asserts the refresh acknowledge signal to indicate that it has issued a refresh command to the ALTMEMPHY megafunction. This signal is still available even if the **Enable user auto-refresh controls** option is not on, allowing the user logic to track when the controller issues refreshes.
3. The user logic keeps the refresh request signal asserted to indicate that it wishes to perform another refresh request.

The controller again asserts the refresh acknowledge signal to indicate that it has issued a refresh. At this point the user logic deasserts the refresh request signal and the controller continues with the reads and writes in its buffers.

Self-Refresh and Power-Down Commands

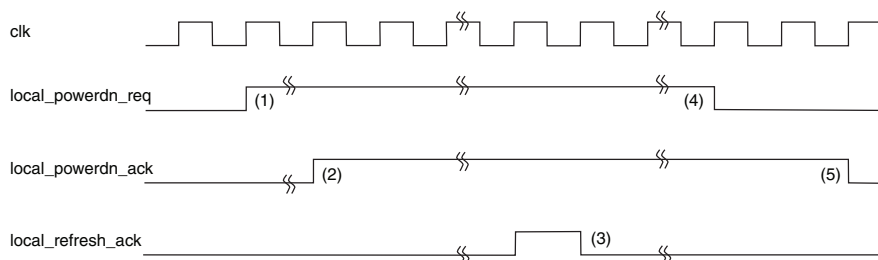
This feature allows you to direct the controller to put the external memory device into a low-power state. There are two possible low-power states: self-refresh and power down. The controller supports both and manages the necessary memory timings to ensure that the data in the memory is maintained at all times.

The local interface input pins (`local_powerdn_req` and `local_self_rfsh_req`) allow you to direct the controller to place the memory device in power-down or self-refresh mode, respectively. The local interface output pins (`local_powerdn_ack`, and `local_self_rfsh_ack`) allow the controller to acknowledge the request and also indicate the current state of the memory.

If either `local_powerdn_ack` or `local_self_rfsh_ack` signal is asserted, the memory is in the relevant low-power mode. Both pairs of signals follow the same basic protocol as shown in Figure 4-8 and Figure 4-9 on page 4-18. The self-refresh pair of signals follows the same timing and behavior as the power-down pair. The only difference is that the `local_refresh_ack` signal is not asserted in self-refresh mode as the controller does not refresh the memory when the memory is in self-refresh mode.

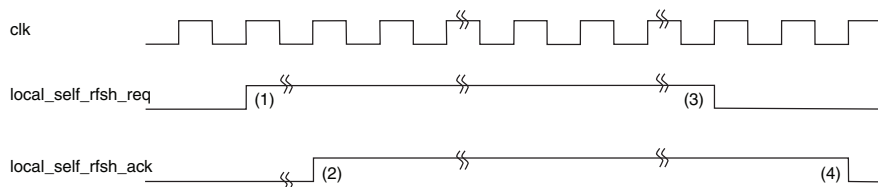
You must not assert both request signals at the same time. Undefined behavior occurs if both `local_powerdn_req` and `local_self_rfsh_req` are asserted simultaneously.

Figure 4-8. Power-Down Mode



Notes to Figure 4-8:

- (1) The user synchronously asserts the request signal to indicate that the controller should put the memory into the power-down state as soon as possible.
- (2) Once the controller is able to issue the correct commands to put the memory into the power-down state, it responds by asserting the acknowledge signal.
- (3) If you direct the controller to hold the memory in power-down mode for longer than a refresh cycle, the controller wakes the memory briefly to issue a refresh command at the required time. The `local_refresh_ack` signal indicates that this has happened - it is asserted for one clock cycle at approximately the same time as the refresh command is issued. If **Enable user auto-refresh controls** is turned on, you must issue refresh requests via the `local_refresh_req` input at the appropriate time, even if the user has also requested power-down mode.
- (4) The controller holds the memory in power-down mode until you deassert the request signal.
- (5) The controller deasserts the acknowledge signal once it has released the memory from the power-down state and once the required timing parameters are met.

Figure 4-9. Self-Refresh Mode**Notes to Figure 4-9:**

- (1) You synchronously assert the request signal to indicate that the controller should put the memory into the self-refresh state as soon as possible.
- (2) Once the controller is able to issue the correct commands to put the memory into the self-refresh state, it responds by asserting the acknowledge signal.
- (3) The controller holds the memory in self-refresh mode until you deassert the request signal.
- (4) The controller deasserts the acknowledge signal once it has released the memory from the self-refresh state and once the required timing parameters are met.

Auto-Precharge Commands

The **auto-precharge read and auto-precharge write commands** allow you to indicate to the memory device that this **read or write command is the last access to the currently open row**. The **memory device automatically closes (auto-precharges) the page it is currently accessing so that the next access to the same bank is quicker. This command is particularly useful for applications that require fast random accesses.**

Request an auto-precharge by asserting the `local_autopch` input at the same time you assert the `local_read_req` or `local_write_req` signal. The timing and rules of the `local_autopch` input follow the basic *Avalon Interface Specifications*. You can assert it anytime, but once you have asserted it, the signal must stay asserted until the `local_ready` signal is high, which indicates that the current request has been accepted.



If your MegaCore variation is configured to support local burst sizes greater than one, note that `local_autopch` is ignored unless you request a complete burst. It is not possible to auto-precharge a partial burst to the memory.

Initialization Timing

The DDR3 SDRAM high-performance controller relies on the ALTMEMPHY megafunction for initialization.



For more information, refer to the *External Memory PHY Interface Megafunction User Guide (ALTMEMPHY)*.

When ALTMEMPHY megafunction has finished calibrating, the memory controller asserts the `local_init_done` signal, which shows that it has initialized the memory devices.

Signals

Table 4-5 shows the clock and reset signals.

Table 4-5. Clock and Reset Signals

Name	Direction	Description
global_reset_n	Input	The asynchronous reset input to the controller. All other reset signals are derived from resynchronized versions of this signal. This signal holds the complete ALTMEMPHY megafunction, including the PLL, in reset while low.
pll_ref_clk	Input	The reference clock input to PLL.
phy_clk	Output	The system clock that the ALTMEMPHY megafunction provides to the user. All user inputs to and outputs from the DDR3 high-performance controller must be synchronous to this clock.
reset_phy_clk_n	Output	The reset signal that the ALTMEMPHY megafunction provides to the user. It is asserted asynchronously and deasserted synchronously to phy_clk clock domain.
dll_reference_clk	Output	Reference clock to feed to an externally instantiated DLL.
reset_request_n	Output	Reset request output that indicates when the PLL outputs are not locked. Use this as a reset request input to any system-level reset controller you may have. This signal is always low while the PLL is locking, and so any reset logic using it is advised to detect a reset request on a falling edge rather than by level detection.
soft_reset_n	Input	Edge detect reset input intended for SOPC Builder use or to be controlled by other system reset logic. It is asserted to cause a complete reset to the PHY, but not to the PLL used in the PHY.
oct_ctl_rs_value	Input	ALTMEMPHY signal that specifies the serial termination value. Should be connected to the ALT_OCT megafunction output <code>seriesterminationcontrol</code> .
oct_ctl_rt_value	Input	ALTMEMPHY signal that specifies the parallel termination value. Should be connected to the ALT_OCT megafunction output <code>parallelerminationcontrol</code> .
dqs_delay_ctrl_import	Input	Allows the use of DLL in another ALTMEMPHY instance in this ALTMEMPHY instance. Connect the <code>export</code> port on the ALTMEMPHY instance with a DLL to the <code>import</code> port on the other ALTMEMPHY instance.

Table 4–6 shows the DDR3 SDRAM high-performance controller local interface signals.

Table 4–6. Local Interface Signals (Part 1 of 3)


Signal Name	Direction	Description
<code>local_address[]</code>	Input	<p>Memory address at which the burst should start. The width of this bus is sized using the following equation:</p> <p>For one chip select:</p> $\text{width} = \text{bank bits} + \text{row bits} + \text{column bits} - 1$ <p>For multiple chip selects:</p> $\text{width} = \text{chip bits} + \text{bank bits} + \text{row bits} + \text{column bits} - 1$ <p>If the bank address is 3 bits wide, row is 14 bits wide and column is 10 bits wide, then the local address is 25 bits wide. To map <code>local_address</code> to bank, row and column address:</p> <p><code>local_address</code> is 25 bits wide</p> $\text{local_address}[24:22] = \text{bank address}[2:0]$ $\text{local_address}[21:8] = \text{row address}[13:0]$ $\text{local_address}[7:0] = \text{col_address}[9:2]$ <p>The two least significant bits (LSB) of the column address on the memory side are ignored, because the local data width is four times that of the memory data bus width.</p> <p> You can get the information on address mapping from the <code><variation_name>_example_top.v</code> or <code>vhd</code> file.</p>
<code>local_be[]</code>	Input	Byte enable signal, which you use to mask off individual bytes during writes.
<code>local_burstbegin</code>	Input	Avalon burst begin strobe, which indicates the beginning of an Avalon burst. This signal is only available when the local interface is an Avalon-MM interface. Unlike all other Avalon-MM signals, the burst begin signal does not stay asserted if <code>local_ready</code> is deasserted.
<code>local_read_req</code>	Input	<p>Read request signal.</p> <p>You cannot assert read request and write request signal at the same time.</p>
<code>local_refresh_req</code>	Input	User controlled refresh request. If Enable user auto-refresh controls is turned on, <code>local_refresh_req</code> becomes available and you are responsible for issuing sufficient refresh requests to meet the memory requirements. This option allows complete control over when refreshes are issued to the memory including ganging together multiple refresh commands. Refresh requests take priority over read and write requests unless they are already being processed.
<code>local_size[]</code>	Input	Controls the number of beats in the requested read or write access to memory, encoded as a binary number. The DDR3 SDRAM high-performance controller supports burst lengths of 1 and 2 on the local side interface.
<code>local_wdata[]</code>	Input	Write data bus. The width of <code>local_wdata</code> is four times the memory data bus for half rate controller.
<code>local_write_req</code>	Input	<p>Write request signal.</p> <p>You cannot assert read request and write request signal at the same time.</p>

Table 4-6. Local Interface Signals (Part 2 of 3)

Signal Name	Direction	Description
local_init_done	Output	<p>When the memory initialization, training, and calibration are complete, the ALTMEMPHY sequencer asserts the <code>ctrl_usr_mode_rdy</code> signal to the memory controller, which then asserts this signal to indicate that the memory interface is ready to be used.</p> <p>Read and write requests are still accepted before <code>local_init_done</code> is asserted, however they are not issued to the memory until it is safe to do so.</p> <p>This signal does not indicate that the calibration is successful. To find out if the calibration is successful, look for the calibration signal, <code>resynchronization_successful</code> or <code>postamble_successful</code> if you are using Stratix IV.</p>
local_rdata[]	Output	Read data bus. The width of <code>local_rdata</code> is four times that of the memory data bus.
local_rdata_error	Output	Asserted if the current read data has an error. This signal is only available if the Enable error detection and correction logic is turned on.
local_rdata_valid	Output	Read data valid signal. The <code>local_rdata_valid</code> signal indicates that valid data is present on the read data bus. The timing of <code>local_rdata_valid</code> is automatically adjusted to cope with your choice of resynchronization and pipelining options.
local_ready	Output	The <code>local_ready</code> signal indicates that the DDR3 SDRAM high-performance controller is ready to accept request signals. If <code>local_ready</code> is asserted in the clock cycle that a read or write request is asserted, that request has been accepted. The <code>local_ready</code> signal is deasserted to indicate that the DDR3 SDRAM high-performance controller cannot accept any more requests.
local_refresh_ack	Output	Refresh request acknowledge, which is asserted for one clock cycle every time a refresh is issued. Even if the Enable user auto-refresh controls option is not selected, <code>local_refresh_ack</code> still indicates to the local interface that the controller has just issued a refresh command.
local_wdata_req	Output	Write data request signal, which indicates to the local interface that it should present valid write data on the next clock edge. This signal is only required when the controller is operating in Native interface mode.
local_autopch_req	Input	User control of precharge. If Enable auto precharge control is turned on, <code>local_autopch_req</code> becomes available and you can request the controller to issue an auto-precharge write or auto-precharge read command. These commands cause the memory to issue a precharge command to the current bank at the appropriate time without an explicit precharge command from the controller. This is particularly useful if you know the current read or write is the last one you intend to issue to the currently open row. The next time you need to use that bank, the access could be quicker as the controller does not need to precharge the bank before activating the row you wish to access.

Table 4-6. Local Interface Signals (Part 3 of 3)

Signal Name	Direction	Description
local_powerdn_req	Input	User control of the power down feature. If Enable power down controls option is enabled, you can request that the controller place the memory devices into a power-down state as soon as it can without violating the relevant timing parameters and responds by asserting the local_powerdn_ack signal. You can hold the memory in the power-down state by keeping this signal asserted. The controller brings the memory out of the power-down state to issue periodic auto-refresh commands to the memory at the appropriate interval if you hold it in the power-down state. You can release the memory from the power-down state at any time by deasserting the local_powerdn_ack signal once it has successfully brought the memory out of the power-down state.
local_powerdn_ack	Output	Power-down request acknowledge signal. This signal is asserted and deasserted in response to the local_powerdn_req signal from the user.
local_self_rfsh_req	Input	User control of the self-refresh feature. If Enable self-refresh controls option is enabled, you can request that the controller place the memory devices into a self-refresh state by asserting this signal. The controller places the memory in the self-refresh state as soon as it can without violating the relevant timing parameters and responds by asserting the local_self_rfsh_ack signal. You can hold the memory in the self-refresh state by keeping this signal asserted. You can release the memory from the self-refresh state at any time by deasserting the local_self_rfsh_req signal and the controller responds by deasserting the local_self_rfsh_ack signal once it has successfully brought the memory out of the self-refresh state.
local_self_rfsh_ack	Output	Self refresh request acknowledge signal. This signal is asserted and deasserted in response to the local_self_rfsh_req signal from the user.

Table 4-7 shows the DDR3 SDRAM interface signals.

Table 4-7. DDR3 SDRAM Interface Signals (Part 1 of 2)

Signal Name	Direction	Description
mem_dq[]	Bidirectional	Memory data bus. This bus is half the width of the local read and write data busses.
mem_dqs[]	Bidirectional	Memory data strobe signal, which writes data into the DDR3 SDRAM and captures read data into the Altera device.
mem_dqs_n[]	Bidirectional	Memory data strobe signal, which writes data into the DDR3 SDRAM and captures read data into the Altera device.
mem_clk (1)	Bidirectional	Clock for the memory device.
mem_clk_n (1)	Bidirectional	Inverted clock for the memory device.
mem_a[]	Output	Memory address bus.
mem_ba[]	Output	Memory bank address bus.
mem_cas_n	Output	Memory column address strobe signal.
mem_cke[]	Output	Memory clock enable signals.
mem_cs_n[]	Output	Memory chip select signals.
mem_dm[]	Output	Memory data mask signal, which masks individual bytes during writes.

Table 4-7. DDR3 SDRAM Interface Signals (Part 2 of 2)

Signal Name	Direction	Description
mem_odt []	Output	Memory on-die termination control signal.
mem_ras_n	Output	Memory row address strobe signal.
mem_reset_n	Output	Memory reset signal.
mem_we_n	Output	Memory write enable signal.

Note to Table 4-7:

- (1) The mem_clk signals are output only signals from the FPGA. However, in the Quartus II software they must be defined as bidirectional (INOUT) I/Os to support the mimic path structure that the ALTMEMPHY megafunction uses.

Table 4-8 shows the ECC controller signals.

Table 4-8. ECC Controller Signals

Signal Name	Direction	Description
ecc_addr []	Input	Address for ECC controller.
ecc_be []	Input	ECC controller byte enable.
ecc_interrupt	Output	Interrupt from ECC controller.
ecc_rdata []	Output	Return data from ECC controller.
ecc_read_req	Input	Read request for ECC controller.
ecc_wdata []	Input	ECC controller write data.
ecc_write_req	Input	Write request for ECC controller.

This appendix describes the ECC registers and the register bits.

ECC Registers

Table A-1 shows the ECC registers.

Table A-1. ECC Registers (Part 1 of 2)

Name	Address	Size (Bits)	Attribute	Default	Description
Control word specifications	00	32	R/W	0000000F	This register contains all commands for the ECC functioning.
Maximum single-bit error counter threshold	01	32	R/W	00000001	The single-bit error counter increments (when a single-bit error occurs) until the maximum threshold, as defined by this register. When this threshold is crossed, the ECC generates an interrupt.
Maximum double-bit error counter threshold	02	32	R/W	00000001	The double-bit error counter increments (when a double-bit error occurs) until the maximum threshold, as defined by this register. When this threshold is crossed, the ECC generates an interrupt.
Current single-bit error count	03	32	RO	00000000	The single-bit error counter increments (when a single-bit error occurs) until the maximum threshold. You can find the value of the count by reading this status register.
Current double-bit error count	04	32	RO	00000000	The double-bit error counter increments (when a double-bit error occurs) until the maximum threshold. You can find the value of the count by reading this status register.
Last or first single-bit error error address	05	32	RO	00000000	This status register stores the last single-bit error error address. It can be cleared using the control word clear. If bit 10 of the control word is set high, the first occurred address is stored.
Last or first double-bit error error address	06	32	RO	00000000	This status register stores the last double-bit error error address. It can be cleared using the control word clear. If bit 10 of the control word is set high, the first occurred address is stored.

Table A-1. ECC Registers (Part 2 of 2)

Name	Address	Size (Bits)	Attribute	Default	Description
Last single-bit error error data	07	32	RO	00000000	This status register stores the last single-bit error error data word. As the data word is an M th multiple of 64, the data word is stored in a $2N$ -deep, 32-bit wide FIFO buffer with the least significant 32-bit sub word stored first. It can be cleared individually by using the control word clear.
Last single-bit error syndrome	08	32	RO	00000000	This status register stores the last single-bit error syndrome, which specifies the location of the error bit on a 64-bit data word. As the data word is an M th multiple of 64, the syndrome is stored in a N deep, 8-bit wide FIFO buffer where each syndrome represents errors in every 64-bit part of the data word. The register gets updated with the correct syndrome depending on which part of the data word is shown on the last single-bit error error data register. It can be cleared individually by using the control word clear.
Last double-bit error error data	09	32	RO	00000000	This status register stores the last double-bit error error data word. As the data word is an M th multiple of 64, the data word is stored in a $2N$ deep, 32-bit wide FIFO buffer with the least significant 32-bit sub word stored first. It can be cleared individually by using the control word clear.
Interrupt status register	0A	5	RO	00000000	This status register stores the interrupt status in four fields (refer to Table A-3). These status bits can be cleared by writing a 1 in the respective locations.
Interrupt mask register	0B	5	WO	00000001	This register stores the interrupt mask in four fields (refer to Table A-4).
Single-bit error location status register	0C	32	R/W	00000000	This status register stores the occurrence of single-bit error for each 64-bit part of the data word in every bit (refer to Table A-5). These status bits can be cleared by writing a 1 in the respective locations.
Double-bit error location status register	0D	32	R/W	00000000	This status register stores the occurrence of double-bit error for each 64-bit part of the data word in every bit (refer to Table A-6). These status bits can be cleared by writing a 1 in the respective locations.

Register Bits

Table A-2 shows the control word specification register.

Table A-2. Control Word Specification Register

Bit	Name	Direction	Description
0	Count single-bit error	Decoder-corrector	When 1, count single-bit errors.
1	Correct single-bit error	Decoder-corrector	When 1, correct single-bit errors.
2	Double-bit error enable	Decoder-corrector	When 1, detect all double-bit errors and increment double-bit error counter.
3	Reserved	N/A	Reserved for future use.
4	Clear all status registers	Controller	When 1, clear counters single-bit error and double-bit error status registers for first and last error address.
5	Reserved	N/A	Reserved for future use.
6	Reserved	N/A	Reserved for future use.
7	Counter clear on read	Controller	When 1, enables counters to clear on read feature.
8	Corrupt ECC enable	Controller	When 1, enables deliberate ECC corruption during encoding, to test the ECC.
9	ECC corruption type	Controller	When 0, creates single-bit errors in all ECC codewords; when 1, creates double-bit errors in all ECC codewords.
10	First or last error	Controller	When 1, stores the first error address rather than the last error address of single-bit error or double-bit error.
11	Clear interrupt	Controller	When 1, clears the interrupt.

Table A-3 shows the interrupt status register.

Table A-3. Interrupt Status Register

Bit	Name	Description
0	Single-bit error	When 1, single-bit error occurred.
1	Double-bit error	When 1, double-bit error occurred.
2	Maximum single-bit error	When 1, single-bit error maximum threshold exceeded.
3	Maximum double-bit error	When 1, double-bit error maximum threshold exceeded.
4	Double-bit error during read-modify-write	When 1, double-bit error occurred during a read modify write condition. (partial write).
Others	Reserved	Reserved.

Table A-4 shows the interrupt mask register.

Table A-4. Interrupt Mask Register

Bit	Name	Description
0	Single-bit error	When 1, masks single-bit error.
1	Double-bit error	When 1, masks double-bit error.
2	Maximum single-bit error	When 1, masks single-bit error maximum threshold exceeding condition.
3	Maximum double-bit error	When 1, masks double-bit error maximum threshold exceeding condition.
4	Double-bit error during read-modify-write	When 1, masks interrupt when double-bit error occurs during a read-modify-write condition. (partial write).
Others	Reserved	Reserved.

Table A-5 shows the single-bit error location status register.

Table A-5. Single-Bit Error Location Status Register

Bit	Name	Description
Bits $N-1$ down to 0	Interrupt	When 0, no single-bit error; when 1, single-bit error occurred in this 64-bit part.
Others	Reserved	Reserved.

Table A-6 shows the double-bit error location status register.

Table A-6. Double-Bit Error Location Status Register

Bit	Name	Description
Bits $N-1$ down to 0	Cause of Interrupt	When 0, no double-bit error; when 1, double-bit error occurred in this 64-bit part.
Others	Reserved	Reserved.

Revision History

The following table shows the revision history for this user guide.

Date	Version	Changes Made
March 2009	9.0	<ul style="list-style-type: none"> Updated device support for Arria II GX and Stratix III. Removed Appendix B.
November 2008	8.1	<ul style="list-style-type: none"> Updated section on Example Driver. Added new section on DDR3 SDRAM High-Performance Controller Architecture. Added new section on Simulating With Other Simulators - VHDL/Verilog HDL IP. Functional Simulation.
May 2008	8.0	<ul style="list-style-type: none"> Added a section on ECC. Added more detailed ECC information (Appendix A). Added more detailed latency information (Appendix B). Added Stratix IV support.
October 2007	7.2	First release.

How to Contact Altera

For the most up-to-date information about Altera products, see the following table.






Contact <i>(Note 1)</i>	Contact Method	Address
Technical support	Website	www.altera.com/support
Technical training	Website	www.altera.com/training
	Email	custrain@altera.com
Altera literature services	Email	literature@altera.com
Non-technical support (General) (Software Licensing)	Email	nacomp@altera.com
	Email	authorization@altera.com

Note:

(1) You can also contact your local Altera sales office or sales representative.

Typographic Conventions

The following table shows the typographic conventions that this document uses.

Visual Cue	Meaning
Bold Type with Initial Capital Letters	Indicates command names, dialog box titles, dialog box options, and other GUI labels. For example, Save As dialog box.
bold type	Indicates directory names, project names, disk drive names, file names, file name extensions, and software utility names. For example, qdesigns directory, d: drive, and chiptrip.gdf file.
<i>Italic Type with Initial Capital Letters</i>	Indicates document titles. For example, <i>AN 519: Stratix IV Design Guidelines</i> .
<i>Italic type</i>	Indicates variables. For example, $n + 1$. Variable names are enclosed in angle brackets (< >). For example, <file name> and <project name>.pof file.
Initial Capital Letters	Indicates keyboard keys and menu names. For example, Delete key and the Options menu.
“Subheading Title”	Quotation marks indicate references to sections within a document and titles of Quartus II Help topics. For example, “Typographic Conventions.”
Courier type	Indicates signal, port, register, bit, block, and primitive names. For example, data1, tdi, and input. Active-low signals are denoted by suffix n. For example, resetn. Indicates command line commands and anything that must be typed exactly as it appears. For example, c:\qdesigns\tutorial\chiptrip.gdf. Also indicates sections of an actual file, such as a Report File, references to parts of files (for example, the AHDL keyword SUBDESIGN), and logic function names (for example, TRI).
1., 2., 3., and a., b., c., and so on.	Numbered steps indicate a list of items when the sequence of the items is important, such as the steps listed in a procedure.
■ ■	Bullets indicate a list of items when the sequence of the items is not important.
	The hand points to information that requires special attention.
	A caution calls attention to a condition or possible situation that can damage or destroy the product or your work.
	A warning calls attention to a condition or possible situation that can cause you injury.
	The angled arrow instructs you to press Enter.
	The feet direct you to more information about a particular topic.